



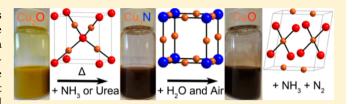
# Preparation and Instability of Nanocrystalline Cuprous Nitride

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Supporting Information

**ABSTRACT:** Low-dimensional cuprous nitride  $(Cu_3N)$  was synthesized by nitridation (ammonolysis) of cuprous oxide  $(Cu_2O)$  nanocrystals using either ammonia  $(NH_3)$  or urea  $(H_2NCONH_2)$  as the nitrogen source. The resulting nanocrystalline  $Cu_3N$  spontaneously decomposes to nanocrystalline CuO in the presence of both water and oxygen from air at room temperature. Ammonia was produced in 60% chemical yield during  $Cu_3N$  decomposition, as measured using the



colorimetric indophenol method. Because  $Cu_3N$  decomposition requires  $H_2O$  and produces substoichiometric amounts of  $NH_3$ , we conclude that this reaction proceeds through a complex stoichiometry that involves the concomitant release of both  $N_2$  and  $NH_3$ . This is a thermodynamically unfavorable outcome, strongly indicating that  $H_2O$  (and thus  $NH_3$  production) facilitate the kinetics of the reaction by lowering the energy barrier for  $Cu_3N$  decomposition. The three different  $Cu_2O$ ,  $Cu_3N$ , and CuO nanocrystalline phases were characterized by a combination of optical absorption, powder X-ray diffraction, transmission electron microscopy, and electronic density of states obtained from electronic structure calculations on the bulk solids. The relative ease of interconversion between these interesting and inexpensive materials bears possible implications for catalytic and optoelectronic applications.

# ■ INTRODUCTION

Copper(I) nitride ( $Cu_3N$ ) is a metastable semiconductor that has a low reflectivity and high electrical resistivity. It has been reported to have a narrow experimental band gap of 1.2–1.9  $eV^2$  and features a cubic anti-ReO $_3$  structure. Because of these properties,  $Cu_3N$  nanocrystals (NCs) are promising materials for optical storage devices, random access memory chips, conductive inks, high-speed integrated circuits, microscopic metal links, photocatalysts, and electrocatalytic hydrogen reduction devices.  $^{1-3}$ 

 $\text{Cu}_3N$  NCs can be synthesized by several methods.  $\text{Cu}_3N$  nanocubes were synthesized by the one-pot decomposition of copper(II) nitrate in octadecene, octadecylamine, and oleylamine.  $^{1,2,4,5}$  Copper nitride nanocrystals were also produced by decomposing  $\text{Cu}(\text{OAc})_2$  with ammonia,  $^{3,6-9}$  a metastable  $\text{CuCl}_2\text{-sodium}$  azide precursor,  $^{10}$  or  $\{[\text{Cu}_5(\text{CN})_6\text{-}(\text{NH}_3)_6(\text{N}_3)_2]\}_n$ .  $^{11}$  Cu\_3N nanopowders were produced by ammonolysis of  $\text{CuF}_2$ .  $^{12}$  Cu\_4N and Cu\_3N\_2 nanostructures have been prepared as thin films.  $^{13-16}$ 

A versatile route for making nitrides and oxynitrides is the nitridation (ammonolysis) of metal oxides. CuO has been used as a precursor to Cu<sub>3</sub>N. Silica-supported CuO nanoparticles were converted to Cu<sub>3</sub>N by nitridation with ammonia. Nitridation of sol—gel CuO with ammonia produced silica-supported Cu<sub>3</sub>N nanocrystals. Ammonia is believed to reduce CuO to a zerovalent (metallic) copper intermediate during nitride formation.

Cupric  $(Cu^{2+})$  and cuprous  $(Cu^{+})$  oxide nanocrystals are well described in the literature. The synthesis, characterization, and optoelectronic properties of CuO nanostructures have been reviewed. Like CuO nanocrystals, nitridation of  $Cu_2O$ 

nanocrystals could also lead to Cu<sub>3</sub>N. Controlled syntheses (monodispersity, size, morphology) of Cu<sub>2</sub>O nanocrystals by electrodeposition, wet chemical, and solvothermal methods exist, along with reports on their surface, catalytic, and electrical properties. <sup>20,22,23</sup>

An interesting feature of  $Cu_3N$  is its documented decomposition upon heating or electron bombardment. For example,  $Cu_3N$  thin films convert to CuO nanowire arrays by annealing in air.  $^{24}$   $Cu_3N$  deposited by magnetic sputtering converts to Cu and  $N_2$  under electron bombardment or by annealing in a vacuum.  $^{25,26}$  The optical properties of  $Cu_3N$  thin films made by ion-assisted deposition remained unchanged upon conducting an aging test at 60 °C and 95% humidity for 15 months, but degraded to copper metal when heated to 300 °C.  $^{27}$   $Cu_3N$  nanoparticles were reported to degrade thermally, forming CuO at temperatures ranging between 200 and 330 °C under an argon atmosphere.  $^3$ 

In this work, we synthesize  $Cu_3N$  nanocrystals by nitridation of  $Cu_2O$  nanocrystals with either ammonia or urea. We characterize the structure, optical properties, and morphology of both oxide and nitride phases using structural, optical, and computational methods. We also describe the spontaneous room-temperature decomposition of  $Cu_3N$  nanocrystals upon exposure to moisture and air, and used simple thermodynamics calculations to explain that the observed concomitant release of  $NH_3$  and  $N_2$  is due to kinetic factors.

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#### **■ EXPERIMENTAL SECTION**

**Materials.** Copper(II) chloride dihydrate (CuCl $_2$ ·2H $_2$ O, 99.0%) and sodium nitroprusside dihydrate (Na $_2$ [Fe(CN) $_5$ NO]·2H $_2$ O, 99.0%) were purchased from Sigma-Aldrich; ammonium carbonate ((NH $_4$ ) $_2$ CO $_3$ , tech.), ascorbic acid (C $_6$ H $_8$ O $_6$ , tech.), and sodium hydroxide (NaOH, tech.) from Fisher; urea (H $_2$ NCONH $_2$ , tech.) and phenol (C $_6$ H $_5$ OH, tech.) from Alfa Aesar; ammonia gas (NH $_3$ , 99.99%) from Airgas; and sodium hypochlorite (NaOCl, 8.25%) from Clorox. All chemicals were used as received.

**Synthesis.** Cu<sub>2</sub>O Nanocrystals. Cu<sub>2</sub>O nanocrystals were made by a modified literature procedure:<sup>28</sup> Briefly, 100 mL of a 0.4 M NaOH solution was added to 100 mL of a 0.2 M CuCl<sub>2</sub> solution. After the solution was stirred for 5 min, 100 mL of a 0.2 M C<sub>6</sub>H<sub>8</sub>O<sub>6</sub> was added. The mixture was stirred for 25 min and centrifuged. The precipitate was collected, washed three times with distilled water and once with ethanol, and dried at room temperature (R.T., ca. 21-24 °C) for 12 h. Cu<sub>2</sub>N nanocrystals from ammonia. Cu<sub>2</sub>O nanocrystals (0.15 g) were placed in an alumina combustion boat and put in a fused silica tube inside of a tube furnace (Lindberg 55035). The tube was purged with NH<sub>3</sub> (60 mL/min) for 30 min and then heated to 250 °C for 21 h. Cu<sub>2</sub>N nanocrystals from urea. Cu<sub>2</sub>O nanocrystals (0.15 g) were weighed along with H<sub>2</sub>NCONH<sub>2</sub> (0.126 g) into a Teflon liner inside a 23 mL steel autoclave. The autoclave was placed in a Thomas Scientific (5300A25) muffle furnace and heated to 190 °C (10 °C/min ramp rate, 6 h dwell time). CuO from Cu<sub>3</sub>N decomposition. Cu<sub>3</sub>N (~100 mg, synthesized using either NH3 or H2NCONH2) was exposed to deionized water (10 mL) for 15 days. The product was isolated by centrifugation (4500 rpm, 10 min). To determine the amount of ammonia released during the  $\text{Cu}_3\text{N}$  decomposition reaction, we used the *indophenol method*. <sup>29,30</sup> Solution A:  $\text{C}_6\text{H}_5\text{OH}$  (5 g, 53 mmol) and Na<sub>2</sub>[Fe(CN)<sub>5</sub>NO]·2H<sub>2</sub>O (0.025 g, 0.084 mmol) were dissolved in deionized water (500 mL) using a volumetric flask. Solution B: NaOH (2.5 g, 62.5 mmol) was dissolved in deionized water, NaOCl (8.25%, 4.2 mL) added, and solution diluted with deionized water to 500 mL in a volumetric flask. The two solutions were stored in amber bottles at ca. 8-10 °C using a refrigerator and used within 2 weeks. Seven different calibration solutions were made using solution A (5 mL) and a 0.5 mM solution of  $(\mathrm{NH_4})_2\mathrm{CO_3}$  in deionized water (0 to 350  $\mu\mathrm{L}$  in 50  $\mu$ L increments). Solution B (5 mL) was added and the mixture was stirred at 37 °C for 20 min. Absorbance values at  $\lambda = 623$  nm were used to construct the calibration curve. After centrifugation to isolate the CuO during Cu<sub>3</sub>N decomposition, the same indophenol method was used to analyze the supernatant solutions (100  $\mu$ L) for NH<sub>3</sub> content. Values reported are three-run averages.

**Structural Characterization.** *X-ray Diffraction.* Powder X-ray diffraction (XRD) data were measured using Cu K $\alpha$  radiation on a Rigaku Ultima U4 difractometer. Sample percent composition was determined using PowderCell 2.4 (PCW) refined against standard XRD patterns for Cu<sub>2</sub>O, Cu<sub>3</sub>N, and CuO. Single-crystalline domain sizes were calculated using the Scherrer equation and the typical uncertainty estimated to be  $\pm 0.2$  nm. *Transmission Electron Microscopy.* Transmission electron microscopy (TEM) was conducted on carbon-coated copper grids using a FEI Tecnai G2 F20 field emission scanning transmission electron microscope (STEM) at 200 kV (point-to-point resolution <0.25 nm, line-to-line resolution <0.10 nm). Particle dimensions were measured manually and/or by using ImageJ. Size measurements and particle statistics were obtained for at least >100 particles. Average sizes  $\pm$  standard deviations are reported.

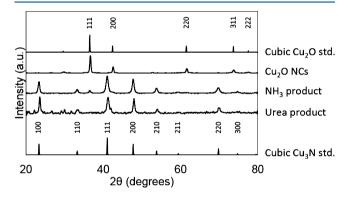
**Optical Characterization.** Absorption spectra were measured using a photodiode array Agilent 8453 UV—vis spectrophotometer. Solvent absorption was subtracted from all spectra. Diffuse reflectance measurements were made using a StellarNet Inc. Black-Comet-SR spectrometer (200–1080 nm).

**Density of States (DOS) Calculations.** Electronic structure calculations of CuO, Cu<sub>2</sub>O, and Cu<sub>3</sub>N were performed using the Vienna Ab initio Simulation Package (VASP).  $^{31,32}$  All VASP calculations were performed using projected augmented-wave (PAW) pseudopotentials with a cutoff energy of 500 eV and a convergence energy of  $1 \times 10^{-6}$  eV.  $^{33}$  A conjugated algorithm was

applied for the structural optimization with a 15  $\times$  15  $\times$  15 Monkhorst-pack k-points grid. The During structure optimization, atomic coordinates and cell volumes were allowed to optimize. Total energies were calculated using the tetrahedron method with Blöchl corrections applied. All VASP calculations treated exchange and correlation by the Perdew-Burke-Enzerhoff (PBE) method. Because of the highly correlated nature of these compounds, on-site Coulomb interactions were used (LDA + U). The U value applied was 5.0 eV for the Cu d states due to this value being successful for previous studies on strongly correlated Cu compounds.  $^{37,38}$ 

#### ■ RESULTS AND DISCUSSION

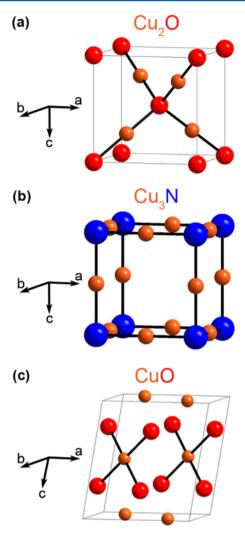
**Synthesis of Cu<sub>2</sub>O Nanocrystals.** On the basis of previous reports of successful nitridation of CuO, we attempted to perform a similar reaction using nanocrystalline  $Cu_2O$  as the starting material. We first synthesized  $Cu_2O$  nanocrystals by reacting copper(II) chloride and sodium hydroxide using a modified literature procedure. This reaction proceeds through a blue copper-hydroxide intermediate, which upon treatment with ascorbic acid produces an orange solution of  $Cu_2O$ . X-ray diffraction confirmed the formation of cubic copper(I) oxide  $(Cu_2O)$  nanocrystals (Figures 1 and 2a). The unit cell of  $Cu_2O$ 



**Figure 1.** Experimental powder XRD patterns before and after treating  $Cu_2O$  nanocrystals with ammonia  $(NH_3)$  or urea  $(H_2NCONH_2)$ . Reported powder XRD patterns for bulk cubic  $Cu_2O$  and cubic (anti-ReO<sub>3</sub>)  $Cu_3N$  are shown for comparison.

consists of a body-centered cubic (bcc) arrangement of oxide ions ( $O^{2-}$ ) with two-coordinate cuprous ions ( $Cu^+$ ) linking every second corner with the central oxide (Figure 2a). The size of the  $Cu_2O$  nanocrystals, as estimated from XRD peak widths using the Scherrer equation, is approximately 25 nm. Figure 3 shows the general appearance and optical absorption of the  $Cu_2O$  nanocrystals. Absorption starts at 600 nm for both the diffuse reflectance of a solid film and the solution phase absorption spectrum of the  $Cu_2O$  nanocrystals, which roughly agree with a reported experimental  $Cu_2O$  band gap of 2.2 eV (see calculated vs experimental band gap discussion below). TEM shows that the  $Cu_2O$  nanocrystals have a cubic morphology, with an average size of 43  $\pm$  10 nm (Figure 4). Table 1 summarizes these observations.

**Nitridation of Cu<sub>2</sub>O Nanocrystals.** We used two different reagents to nitride nanocrystals of Cu<sub>2</sub>O to produce Cu<sub>3</sub>N, namely, ammonia (NH<sub>3</sub>) and urea (H<sub>2</sub>NCONH<sub>2</sub>) (eqs 1 and 2, respectively, in Scheme 1). XRD shows that, in both cases, the main product is made of anti-ReO<sub>3</sub> Cu<sub>3</sub>N nanocrystals with Scherrer sizes of 15 nm (NH<sub>3</sub>) and 22 nm (urea) (Figure 1 and Table 1). The cubic, anti-ReO<sub>3</sub>-type unit cell of Cu<sub>3</sub>N consists of a primitive cubic arrangement of nitride ions with two-coordinate cuprous ions linking every two neighboring nitrides



**Figure 2.** Crystalline unit cells for cubic (a = 4.27 Å) (cuprite) Cu<sub>2</sub>O (a), cubic (a = 3.81 Å) (anti-ReO<sub>3</sub>) Cu<sub>3</sub>N (b), and monoclinic (a = 4.68 Å, b = 3.47 Å, c = 5.12 Å, and  $\beta = 99.7^{\circ}$ ) (tenorite) CuO (c).

(Figure 2b). The product of nitridation with ammonia contains some unreacted Cu<sub>2</sub>O (6%), while the product of nitridation with urea contains smaller amounts of Cu<sub>2</sub>O (1.6%) and CuO (0.4%) (Table 1). Figure 3 shows diffuse reflectance (solid) and optical absorption (solution) spectra of the Cu<sub>3</sub>N nanocrystals made using ammonia as the nitridation agent as a representative example. These nanocrystals show an absorption band edge of around 700 nm, which very roughly matches different reports of experimental Cu<sub>3</sub>N band gaps between 1.1 eV and 1.9 eV.<sup>39</sup> The absorption spectra of the reddish-brown Cu<sub>3</sub>N nanocrystals in both solid form and in solution demonstrate this red shifting (Figure 3b,c). TEM measurements indicate a reagent-dependent change in nanocrystal morphology upon nitridation. Nitridation with ammonia leads to aggregated, spheroidal Cu<sub>3</sub>N nanocrystals with a size of 22 ± 7 nm (Figure 4b and Table 1). Nitridation with urea leads to aggregated Cu<sub>3</sub>N nanocrystals with a wider range of morphologies, including rods, sheets, and clusters with sizes of 370  $\pm$  160 nm, 310  $\pm$  160 nm, and 220  $\pm$  140 nm, respectively (Figure 4d and Table 1).

**Electronic Structure Calculations.** To gain more insight into the optical properties of the different nanocrystalline copper phases presented here, we performed first-principles

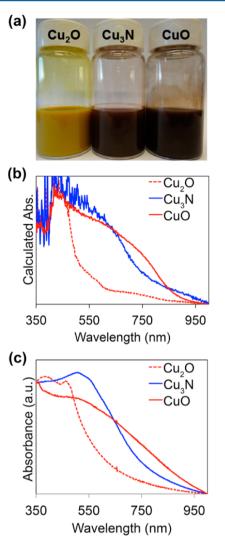


Figure 3. General appearance (suspended in methanol) (a), solid phase diffuse reflectance (b), and solution phase electronic absorption spectra (in methanol) (c) of nanocrystalline  $Cu_2O$ ,  $Cu_3N$ , and CuO.

# Scheme 1

$$Cu_2O_{(s)} + NH_{3(g)} - \frac{250 \text{ °C}}{21 \text{ h}} - Cu_3N_{(s)}$$
 (unbalanced) (1)

$$Cu_2O_{(s)} + (NH_2)_2CO_{(g)} \xrightarrow{190 \text{ °C}} Cu_3N_{(s)}$$
 (unbalanced) (2)

electronic structure calculations on bulk solids to obtain electronic DOS curves (Figure 5). Cu<sub>2</sub>O and Cu<sub>3</sub>N both display similar electronic structures. In both species, a band gap is present at the Fermi level with a magnitude of 0.95 and 0.73 eV for Cu<sub>3</sub>N and Cu<sub>2</sub>O, respectively. This value agrees well with previously reported calculations: Cu<sub>2</sub>O is similar to prior calculations that reported a theoretical value of 0.78; 40 Cu<sub>3</sub>N calculations claimed band gaps that were generally smaller but ranged in theoretical value from 0.23 to 0.9 eV.41 Our calculated band gap for Cu<sub>3</sub>N agrees well with experimental values, while the Cu<sub>2</sub>O band gap is much smaller than those obtained experimentally. An explanation for this discrepancy is the difference between electronic and optical band gaps in  $\text{Cu}_2\text{O}$ . Previous work has found that the direct transition at  $\Gamma$  is forbidden, which leads to no appreciable optical absorption until above 2 eV.42

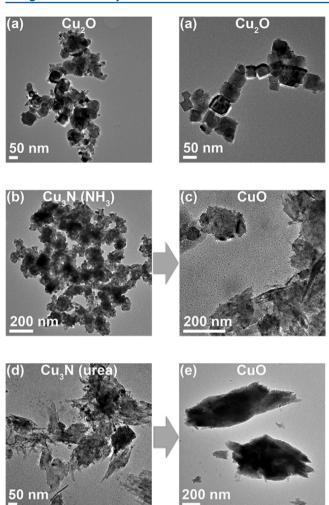
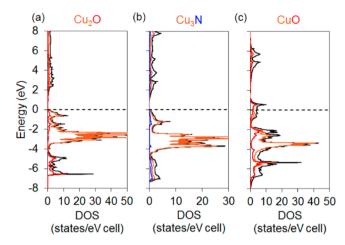


Figure 4. Representative TEM micrographs of nanocrystalline  $Cu_2O$  (a),  $Cu_3N$  made from  $NH_3$  (b) and its decomposition product (c), and  $Cu_3N$  made from urea (d) and its decomposition product (e).

**Spontaneous Decomposition of Cu<sub>3</sub>N to CuO.** During the humid summer time, we observed spontaneous decomposition of the  $Cu_3N$  nanocrystals over a period of several days. To track their fate, we characterized the product using powder XRD, and determined that it was made of nanocrystalline monoclinic (tenorite) CuO (Figure S1, Scheme 2). The tenorite CuO unit cell contains tetracoordinate cupric ( $Cu^{2+}$ ) ions in an approximately square planar configuration (Figure



**Figure 5.** Density of state (DOS) curves for  $Cu_2O$  (a),  $Cu_3N$  (b), and CuO (c). Total DOS is depicted in black. Partial DOS (pDOS) are given in copper (Cu), red (O), and blue (N).

2c). Scherrer particle sizes obtained from XRD are 16 and 12 nm for CuO nanocrystals derived from NH<sub>3</sub>- and urea-made Cu<sub>3</sub>N, respectively. TEM shows that the CuO produced is made of highly aggregated clusters (100–140 nm) of small nanocrystals (13  $\pm$  3 nm) (Figure 4c,e and Table 1).

Reported experimental band gap values for CuO lie in the 1.2–1.5 eV range (see below). The black-colored CuO produced here has a slightly redder absorption edge (ca. 850 nm) than Cu<sub>3</sub>N (Figure 5). DOS calculations show that the electronic structure of CuO is much more complicated than Cu<sub>2</sub>O or Cu<sub>3</sub>N (Figure 5). The most notable feature of the DOS curve for CuO is the peak located at the Fermi level. In traditional band theory, this would indicate CuO is metallic. Along with CoO and NiO, CuO belongs to a class of late metal oxides known as Mott insulators. In addition to the strong Coulombic interactions mentioned above, a recent investigation, focused on elucidating the electronic structure of CuO, found that spin-orbit coupling (SOC) also plays an important role. 45 Without SOC, the valence band ends 1.17 eV above the Fermi level, after which there is a small gap of 0.49 eV, consistent with prior theoretical estimates. 41 However, calculations accounting for SOC found the band gap to start at the Fermi level and be 1.2 eV in magnitude. 45 This value agrees better with experimental values and supports the claim that SOC is an important factor for this class of compounds.

To elucidate what caused the decomposition of  $\text{Cu}_3\text{N}$  nanocrystals, we attempted to react them with water under

Table 1. Synthesis and Instability Studies of Cuprous Nitride Nanocrystals

				dimensions (nm)	
no.	precursors	conditions	XRD	TEM	XRD phase(s) (% composition) <sup>c</sup>
1	$CuCl_{2(aq)} + NaOH + C_6H_8O_6^a$	R.T., <sup>b</sup> 20 min	25	$43 \pm 10$	cubic Cu <sub>2</sub> O (100)
2	$Cu_2O + NH_{3(g)}$	250 °C, 21 h	15	22 ± 7	cubic (anti-ReO <sub>3</sub> ) $Cu_3N$ (94) + cubic $Cu_2O$ (6)
3	$Cu_2O + H_2NCONH_2$ (urea)	190 °C, 6 h	22	$370 \pm 160 \text{ (rods)} 310 \pm 160 \text{ (sheets)}$ $220 \pm 140 \text{ (aggregates)}$	cubic (anti-ReO $_3$ ) Cu $_3$ N (98) + cubic Cu $_2$ O (1.6) + monoclinic (tenorite) CuO (0.4)
4	$Cu_3N$ (from $NH_3$ ) + $H_2O$ + $O_2$ (air)	R.T., <sup>b</sup> 15 days	16	$13 \pm 3$ (dots) $140 \pm 60$ (aggregates)	monoclinic (tenorite) CuO (99.1) + cubic $Cu_2O$ (0.7) + cubic (anti-ReO $_3$ ) $Cu_3N$ (0.2)
5	$Cu_3N$ (from urea) + $H_2O$ + $O_2$ (air)	R.T., <sup>b</sup> 15	12	$100 \pm 70 \text{ (aggregates)}$	CuO monoclinic (100)

<sup>&</sup>quot;Ascorbic acid. b21-24 °C. Sample percent composition was determined using PowderCell 2.4 (PCW) refined against standard XRD patterns for Cu<sub>2</sub>O, Cu<sub>3</sub>N, and CuO.

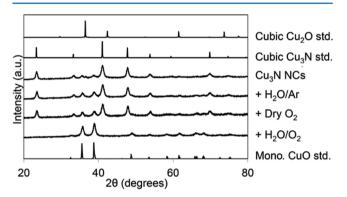
argon (oxygen-free), with dry oxygen (water-free), or with water and oxygen together as control experiments (eqs 3, 4, and 5, respectively, in Scheme 2). As shown in Figure 6,

#### Scheme 2

$$Cu_3N_{(s)} + H_2O_{(l)} \xrightarrow{RT/Ar}$$
 Slow or no reaction (3)

$$Cu_3N_{(s)} + O_{2(g)} \xrightarrow{RT}$$
 Slow or no reaction (4)

$$Cu_3N_{(s)} + H_2O_{(l)} + O_{2(g)} \xrightarrow{RT} CuO_{(s)}$$
 (unbalanced) (5)



**Figure 6.** Experimental powder XRD patterns obtained before and after treating  $Cu_3N$  nanocrystals (NCs) with  $H_2O$  under Ar ( $O_2$ -free), dry  $O_2$  ( $H_2O$ -free), and  $H_2O$  plus  $O_2$ . Reported powder XRD patterns for bulk cubic  $Cu_2O$ , cubic (anti-ReO<sub>3</sub>)  $Cu_3N$ , and monoclinic (tenorite) CuO are shown for comparison (all reactions were performed at R.T. for 15 days).

treating  $Cu_3N$  nanocrystals with water under an oxygen-free Ar atmosphere at room temperature (R.T.) for 15 days did not result in any observable change. The same was true when dry (moisture-free)  $O_2$  was used. In contrast,  $Cu_3N$  completely transformed to nanocrystalline CuO in the presence of both water and  $O_2$  (Figure 6). This reproducible result is independent of the original nitridation source (NH $_3$  or urea) that was employed in making  $Cu_3N$  with very different sizes and morphologies. This result is also consistent with our observation that  $Cu_3N$  decomposition occurred faster during the humid summer months than during the dry winter months.

Tracing the Fate of Nitrogen after Cu<sub>3</sub>N Decomposition. Two nonmutually exclusive, possible nitrogencontaining products of Cu<sub>3</sub>N decomposition are ammonia (NH<sub>3</sub>) and molecular nitrogen (N<sub>2</sub>). We first suspected that NH<sub>3</sub> was produced after observing an increase in the pH of the original solution exposed to the Cu<sub>3</sub>N nanocrystals from slightly acidic or neutral before reaction, to basic after the decomposition of Cu<sub>3</sub>N to CuO was complete. To further examine this issue, we sought to confirm whether NH3 was produced and, if so, to measure exactly how much NH3 was produced, using the colorimetric indophenol method (eq 6 in Scheme 3 and Figure S2). 46,47 As shown in Table 2, similar amounts of ammonia were released upon Cu<sub>3</sub>N decomposition regardless of the source of nitrogen originally used for nitridation (NH3 or urea). In all cases, the experimentally measured chemical yield of NH3 remained constant and equal to 60% relative to the initial amount of Cu<sub>3</sub>N.

Scheme 3. Colorimetric Indophenol Quantification of NH<sub>3</sub>

$$NH_{3(aq)} \xrightarrow[Na_{2}[Fe(CN)_{5}NO]]{} O^{-Na^{+}_{(aq)}}$$

$$NO^{-Na^{+}_{(aq)}}$$

Table 2. Colorimetric Determination of NH<sub>3</sub> Produced from Cu<sub>3</sub>N Decomposition Using the Indophenol Method

	$Cu_3N^a$	NH <sub>3</sub>		
	moles <sup>a</sup>	moles <sup>b</sup>	% yield <sup>c</sup>	
Cu <sub>3</sub> N (NH <sub>3</sub> )	$5.13 \pm 0.07 \times 10^{-5}$	$3.27 \pm 0.04 \times 10^{-5}$	$63.7 \pm 0.9$	
Cu <sub>2</sub> N (urea)	$5.33 \pm 0.05 \times 10^{-5}$	$2.98 \pm 0.04 \times 10^{-5}$	$56 \pm 1$	

<sup>a</sup>Decomposition reactions were carried out in 10 mL of deionized water. <sup>b</sup>Small, 100  $\mu$ L aliquots were further diluted with 10 mL of deionized water to produce the solutions in Figure S2. <sup>c</sup>Based on the total amount of nitrogen (from Cu<sub>3</sub>N).

Thermodynamic Rationale of CuO Formation. In principle, formation of  $N_2$  or  $NH_3$  from  $Cu_3N$  decomposition (oxidation to CuO) could be rationalized by either of the balanced eqs 7 or 8 (Scheme 4). The enthalpies of formation

#### Scheme 4

$$\text{Cu}_3\text{N}_{(s)} + \frac{3}{2}\text{O}_{2(g)} \xrightarrow{\Delta G_7} 3\text{CuO}_{(s)} + \frac{1}{2}\text{N}_{2(g)}$$
 (7)

$$Cu_3N_{(s)} + {}^5/_2H_2O_{(l)} + {}^3/_4O_{2(g)} \xrightarrow{\Delta G_8} 3CuO_{(s)} + NH_4^+_{(aq)} + HO^-_{(aq)}$$
 (8)

$$Cu_{3}N_{(s)} + \frac{5x}{2}H_{2}O_{(l)} + \frac{(6-3x)}{4}O_{2(g)} \xrightarrow{\Delta G_{9}} 3CuO_{(s)} + xNH_{4}^{+}_{(aq)} + xHO_{(aq)}^{-} + (1-x)/{2}N_{2(g)}$$
(9)

 $(\Delta H_{\rm f})$  of all reactants and products in these equations are known, including those of  ${\rm Cu_3N}~(\Delta H_{\rm f}=77~{\rm kJ/mol})^{48,49}$  and  ${\rm CuO}~(\Delta H_{\rm f}=-157.3~{\rm kJ/mol})^{50}$  (near standard conditions). Using these values, the enthalpies of reactions  $(\Delta H_{\rm r})$  (7) and (8) are calculated to be  $-549~{\rm kJ/mol}$  and  $-197~{\rm kJ/mol}$ , respectively. Therefore, decomposition of  ${\rm Cu_3N}$  exclusively to  ${\rm N_2}$  vs  ${\rm NH_3}$  (reaction 7 vs 8) is favored enthalpically by ca. 350 kJ/mol (Figure 7). In other words, there is an inverse relationship between the enthalpy of the  ${\rm Cu_3N}$  decomposition

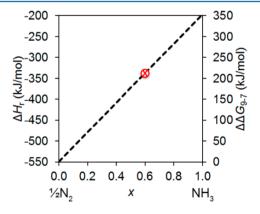


Figure 7. Change in enthalpy  $(\Delta H_r)$  and free energy  $(\Delta G_r)$  of  $Cu_3N$  decomposition to CuO as a function of  $NH_3$  chemical yield (percent = 100x). The circled cross marker in red represents the  $NH_3$  yield (x) observed in this study.

and the amount of  $N_2$  produced by this reaction (relative to NH<sub>3</sub>). Unfortunately, we are presently unable to exactly calculate the free energies ( $\Delta G_r$ ) of reactions (7) and (8), because the free energy of formation ( $\Delta G_f$ ) of Cu<sub>3</sub>N remains unknown.

In spite of the large enthalpic preference for exclusive  $N_2$  production, this was not observed experimentally. On the basis of our observations that  $H_2O$  is required for  $Cu_3N$  decomposition to occur and that  $NH_3$  is produced in 60% yield based on the initial amount of  $Cu_3N$  (x=0.6, Table 2), we conclude that this reaction proceeds through a complex stoichiometry that involves the concomitant release of both  $N_2$  and  $NH_3$ , according to eq 9. We are able to calculate the true thermodynamic cost of ammonia production by considering the difference in Gibb's free energies between reactions 9 and 7 ( $\Delta\Delta G_{9-7}$ ), as follows:

$$\begin{split} \Delta \Delta G_{9-7} &= \Delta G_9 - \Delta G_7 = x \Delta G_{\mathrm{NH_4}^+(\mathrm{aq})}^{\mathrm{f}} + x \Delta G_{\mathrm{HO}^-(\mathrm{aq})}^{\mathrm{f}} \\ &- \frac{5x}{2} \Delta G_{\mathrm{H_2O(l)}}^{\mathrm{f}} + \frac{x}{2} \Delta G_{\mathrm{N_2(g)}}^{\mathrm{f}} - \frac{3x}{4} \Delta G_{\mathrm{O_2(g)}}^{\mathrm{f}} \end{split}$$

In this equation,  $3\Delta G^f_{\text{CuO(s)}}$  and  $\Delta G^f_{\text{Cu<sub>3</sub>N(s)}}$  have been canceled out. In addition, by definition both  $\Delta G^f_{\text{N<sub>2</sub>(g)}}$  and  $\Delta G^f_{\text{O<sub>2</sub>(g)}}$  are zero under ideal or near-ideal conditions (25 °C, 1 atm). This yields

$$\Delta\Delta G_{9-7} = x\Delta G_{NH_4^+(aq)}^f + x\Delta G_{HO^-(aq)}^f - \frac{5x}{2}\Delta G_{H_2O(l)}^f$$
  
= -x(79 kJ/mol) - x(157 kJ/mol)  
+ (5x/2)(237 kJ/mol)<sup>47</sup> = x(358 kJ/mol)

Figure 7 shows a plot of  $\Delta\Delta G_{9-7}$  as a function of chemical yield of NH<sub>3</sub> based on the initial amount of Cu<sub>3</sub>N. The experimentally observed value of 60% is 72 kJ/mol less favorable by free energy compared to when (if) no ammonia is produced. This strongly indicates that the role of H<sub>2</sub>O (and thus NH<sub>3</sub> production) is to facilitate the kinetics of the reaction by lowering the energy barrier for Cu<sub>3</sub>N decomposition to CuO.

# CONCLUSION

In summary, nanocrystalline  $Cu_3N$  was synthesized from nanocrystalline  $Cu_2O$  and one of two nitrogen sources, ammonia  $(NH_3)$  or urea  $(H_2NCONH_2)$ . Using urea leads to slightly more phase-pure  $Cu_3N$ , as observed by XRD. In addition, the use of ammonia as the nitridation (ammonolysis) reagent requires a longer reaction time and higher temperature. TEM reveals that the cubic morphology of the initial  $Cu_2O$  nanocrystals is lost upon nitridation to  $Cu_3N$ . Nitridation with ammonia produces clusters of spherical particles whereas nitridation with urea produced a mixture of several different morphologies (rods, sheets, and aggregates). Electronic structure calculations of the DOS appear to underestimate, but agree with, the presence of a band gap of under 1 eV for both  $Cu_2O$  and  $Cu_3N$  phases.

Cu<sub>3</sub>N nanocrystals spontaneously decompose to nanocrystalline CuO at room temperature. Control experiments show that both air (O<sub>2</sub>, an oxidant) and moisture (H<sub>2</sub>O, for hydrolysis to NH<sub>3</sub>) are necessary for this transformation to take place. Cu<sub>3</sub>N decomposition occurs within 15 days to produce substoichiometric amounts of ammonia. Specifically, ammonia was produced in 60% chemical yield during Cu<sub>3</sub>N decomposition, as measured using the colorimetric indophenol method. Because  $Cu_3N$  decomposition requires  $H_2O$  and produces substoichiometric amounts of  $NH_3$ , we conclude that this reaction proceeds through a complex stoichiometry that involves the concomitant release of both  $N_2$  and  $NH_3$ . This is a thermodynamically unfavorable outcome, strongly indicating that  $H_2O$  (and thus  $NH_3$  production) facilitate the kinetics of the reaction by lowering the energy barrier for  $Cu_3N$  decomposition. Additional studies will be required to assess the potential reversibility and catalytic usefulness of this transformation.

### ASSOCIATED CONTENT

# **S** Supporting Information

Additional XRD, selected area electron-diffraction (SAED) analyses, and solution-phase optical calibration data. The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acs.inorg-chem.5b00679.

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#### Notes

The authors declare no competing financial interest.

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